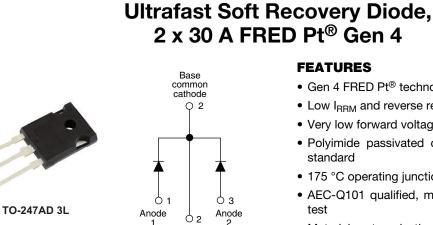
VS-C4PU6006LHN3

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2 3



Common cathode

| PRIMARY CHARACTERISTICS | | | | | |
|----------------------------------|--------------------|--|--|--|--|
| I _{F(AV)} | 2 x 30 A | | | | |
| V _R | 600 V | | | | |
| V _F at I _F | 1.19 V | | | | |
| t _{rr} typ. | See Recovery table | | | | |
| T _J max. | 175 °C | | | | |
| Package | TO-247AD 3L | | | | |
| Circuit configuration | Common cathode | | | | |

FEATURES

- Gen 4 FRED Pt[®] technology
- Low I_{BBM} and reverse recovery charge
- · Very low forward voltage drop
- · Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- AEC-Q101 gualified, meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V_F, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|--|-----------------------------------|---|-------------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS | | | |
| Peak repetitive reverse voltage | V _{RRM} | | 600 | V | | | |
| Average rectified forward current | I _{F(AV)} | T _C = 131 °C | 30 | ٨ | | | |
| Non-repetitive peak surge current, per leg | I _{FSM} | T_C = 25 °C, t_p = 8.3 ms, half sine wave | 240 | A | | | |
| Operating junction and storage temperature | T _J , T _{Stg} | | -55 to +175 | °C | | | |

| ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified) | | | | | | | |
|---|-----------------|--|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Breakdown voltage, blocking voltage | V_{BR}, V_{R} | I _R = 100 μA | 600 | - | - | | |
| Free of all the second s | | I _F = 30 A | - | 1.36 | 1.6 | | |
| | | I _F = 60 A | - | 1.6 | - | V | |
| | V _F | I _F = 30 A, T _J = 125 °C | - | 1.23 | - | | |
| Forward voltage | | I _F = 60 A, T _J = 125 °C | - | 1.5 | - | | |
| | | I _F = 30 A, T _J = 150 °C | - | 1.19 | 1.35 | | |
| | | I _F = 60 A, T _J = 150 °C | - | 1.48 | - | | |
| | | $V_{R} = V_{R}$ rated | - | - | 50 | | |
| Reverse leakage current | I _R | $T_J = 125 \ ^{\circ}C, V_R = V_R \text{ rated}$ | - | - | 500 | μA | |
| Junction capacitance | CT | V _R = 600 V | - | 18.3 | - | pF | |



RoHS COMPLIANT HALOGEN FREE

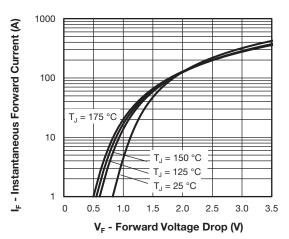
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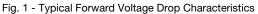


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| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | | |
|---|-----------------|-------------------------|--|------|------|-------|----|--|
| PARAMETER | SYMBOL | TEST C | MIN. | TYP. | MAX. | UNITS | | |
| Bayaraa raaayany tima | + | T _J = 25 °C | L 20 A | - | 65 | - | ns | |
| Reverse recovery time | t _{rr} | T _J = 125 °C | | - | 90 | - | | |
| Peak recovery current | | T _J = 25 °C | I _F = 30 A dI _F /dt = 1000 A/μs | - | 18 | - | А | |
| Feat recovery current | IRRM | T _J = 125 °C | $V_{\rm R} = 400 \text{ V}$ | - | 32 | - | | |
| | Q _{rr} | T _J = 25 °C | | - | 850 | - | nC | |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 1850 | - | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|---------------------------------------|-------------------|------------------------|------------|------|------|------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Thermal resistance, junction to case | R _{thJC} | | - | - | 1 | °C/W | |
| Thermal resistance, case to heat sink | R _{thCS} | | - | 0.4 | - | | |
| Weight | | | - | 6.0 | - | g | |
| Weight | | | - | 0.21 | - | oz. | |
| Mounting torque | | | 6.0 | _ | 12 | kgf · cm | |
| | | | (5) | _ | (10) | (lbf · in) | |
| Marking device | | Case style TO-247AD 3L | C4PU3006LH | | | | |





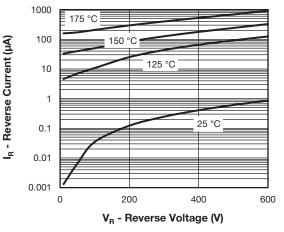


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

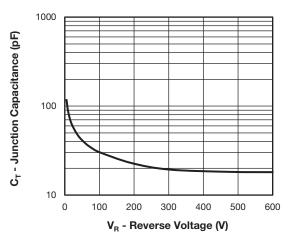
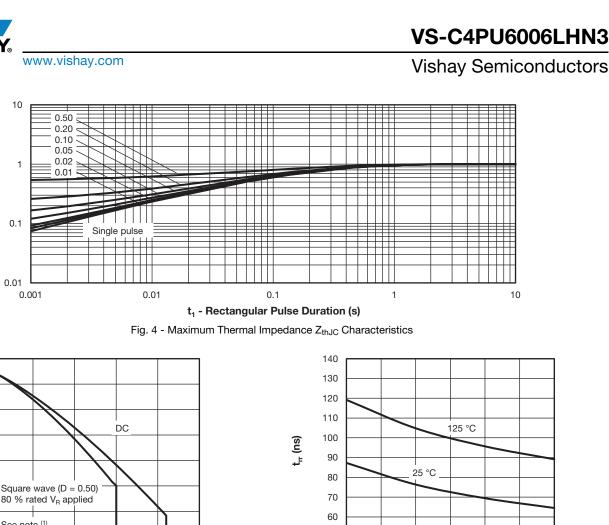


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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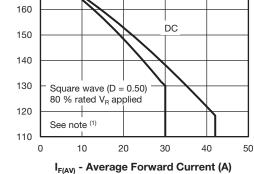


50

400

500

600

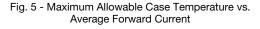


Z_{thJC} - Thermal Impedance Junction to Case (°C/W)

180

170

Allowable Case Temperature (°C)



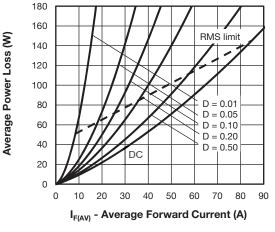


Fig. 6 - Forward Power Loss Characteristics

Note

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⁽¹⁾ Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see Fig.5) P_{dREV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_R = rated V_R

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Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

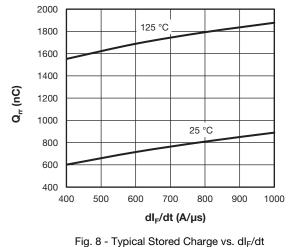
700

dl_r/dt (A/µs)

800

900

1000



VS-C4PU6006LHN3

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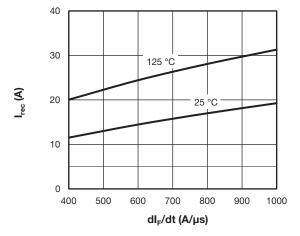


Fig. 9 - Typical Reverse Current vs. dl_F/dt

ORDERING INFORMATION TABLE

| Device code | VS- | С | 4 | Р | U | 60 | 06 | L | н | N3 |
|-------------|------------|------|----------|---|----|---------|-----------|-----------|---------|-------|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 |
| | 1 - 2 - | Circ | uit conf | niconduc | ו: | oduct | | | | |
| | 3 - | FRE | ED Pt G | on diode en 4 [°] packag | | | | | | |
| | 5 - | Pro | cess typ | | | | | | | |
| | 6 - 7 - | | | ng (60 = ng (06 = | | | | | | |
| | 8 - 9 - | | • | = long l 101 qua | | | | | | |
| | 10 - | | | ntal digit: en-free, | | ompliar | nt, and t | otally le | ad (Pb) | -free |

| ORDERING INFORMATION (Example) | | | | | | |
|--|----|-----|-------------------------|--|--|--|
| PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | | | |
| VS-C4PU6006LHN3 | 25 | 500 | Antistatic plastic tube | | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|-------------|--------------------------|--|--|
| Dimensions | TO-247AD 3L | www.vishay.com/doc?95626 | | |
| Part marking information | TO-247AD 3L | www.vishay.com/doc?95007 | | |

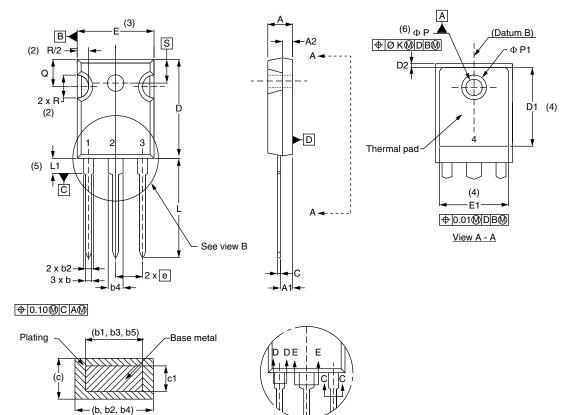
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Vishay Semiconductors

TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

| SYMBOL | MILLIN | IETERS | INCHES | | NOTES |
|----------|--------|--------|--------|-------|-------|
| STIVIBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.65 | 5.31 | 0.183 | 0.209 | |
| A1 | 2.21 | 2.59 | 0.087 | 0.102 | |
| A2 | 1.50 | 2.49 | 0.059 | 0.098 | |
| b | 0.99 | 1.40 | 0.039 | 0.055 | |
| b1 | 0.99 | 1.35 | 0.039 | 0.053 | |
| b2 | 1.65 | 2.39 | 0.065 | 0.094 | |
| b3 | 1.65 | 2.34 | 0.065 | 0.092 | |
| b4 | 2.59 | 3.43 | 0.102 | 0.135 | |
| b5 | 2.59 | 3.38 | 0.102 | 0.133 | |
| с | 0.38 | 0.89 | 0.015 | 0.035 | |
| c1 | 0.38 | 0.84 | 0.015 | 0.033 | |
| D | 19.71 | 20.70 | 0.776 | 0.815 | 3 |
| D1 | 13.08 | - | 0.515 | - | 4 |

(2, 52, 51) (4) Section C - C, D - D, E - E

| SYMBOL | MILLIN | MILLIMETERS | | HES | NOTES |
|--------|----------|-------------|-------|-------|-------|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D2 | 0.51 | 1.30 | 0.020 | 0.051 | |
| E | 15.29 | 15.87 | 0.602 | 0.625 | 3 |
| E1 | 13.46 | - | 0.53 | - | |
| е | 5.46 | BSC | 0.215 | BSC | |
| ØК | 0.2 | 0.254 | |)10 | |
| L | 19.81 | 20.32 | 0.780 | 0.800 | |
| L1 | 3.71 | 4.29 | 0.146 | 0.169 | |
| ØР | 3.56 | 3.66 | 0.14 | 0.144 | |
| Ø P1 | - | 6.98 | - | 0.275 | |
| Q | 5.31 | 5.69 | 0.209 | 0.224 | |
| R | 4.52 | 5.49 | 0.178 | 0.216 | |
| S | 5.51 BSC | | 0.217 | BSC | |

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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